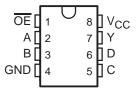
SN74LVC1G99 **ULTRA-CONFIGURABLE MULTIPLE-FUNCTION GATE WITH 3-STATE OUTPL**

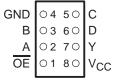
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- Available in Texas Instruments NanoStar™ and NanoFree™ Packages
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max tpd of 6.7 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Offers Nine Different Logic Functions in a Single Package
- Ioff Supports Partial-Power-Down Mode Operation
- Input Hysteresis Allows for Slow Input **Transition Time and Better Noise Immunity** at Input
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DCT OR DCU PACKAGE (TOP VIEW)



YEP OR YZP PACKAGE (BOTTOM VIEW)



description/ordering information

The SN74LVC1G99 is operational from 1.65 V to 5.5 V.

The SN74LVC1G99 features configurable multiple functions with a 3-state output. The output is disabled when the output-enable (\overline{OE}) input is high. When \overline{OE} is low, the output state is determined by 16 patterns of 4-bit input. The user can choose logic functions, such as MUX, AND, OR, NAND, NOR, XOR, XNOR, inverter, and buffer. All inputs can be connected to V_{CC} or GND.

ORDERING INFORMATION

TA	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING‡	
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP Reel of 3000		SN74LVC1G99YEPR	5.5	
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC1G99YZPR	DE_	
-40°C to 85°C	SSOP - DCT	Reel of 3000	SN74LVC1G99DCTR	000	
		Reel of 250	SN74LVC1G99DCTT	C99	
	Veges Boll	Reel of 3000	SN74LVC1G99DCUR	C00	
	VSSOP – DCU	Reel of 250	SN74LVC1G99DCUT	C99_	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site. YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition $(1 = SnPb. \bullet = Pb-free).$



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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SN74LVC1G99 ULTRA-CONFIGURABLE MULTIPLE-FUNCTION GATE WITH 3-STATE OUTPUTS

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description/ordering information (continued)

This device functions as an independent inverter, but because of Schmitt action, it has different input threshold levels for positive-going (V_{T+}) and negative-going (V_{T-}) signals.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

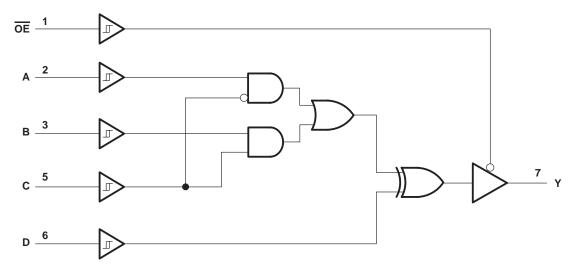
NanoStar[™] and NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

FUNCTION TABLE

	INDUTE								
		INPUTS			OUTPUT				
OE	D	С	В	Α	Υ				
L	L	L	L	L	L				
L	L	L	L	Н	Н				
L	L	L	Н	L	L				
L	L	L	Н	Н	Н				
L	L	Н	L	L	L				
L	L	Н	L	Н	L				
L	L	Н	Н	L	Н				
L	L	Н	Н	Н	Н				
L	Н	L	L	L	Н				
L	Н	L	L	Н	L				
L	Н	L	Н	L	Н				
L	Н	L	Н	Н	L				
L	Н	Н	L	L	Н				
L	Н	Н	L	Н	Н				
L	Н	Н	Н	L	L				
L	Н	Н	Н	Н	L				
Н	H or L	H or L	H or L	H or L	Z				



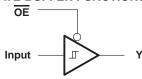
logic diagram (positive logic)



FUNCTION SELECTION TABLE

PRIMARY FUNCTION	COMPLEMENTARY FUNCTION	PAGE
3-state buffer		3
3-state inverter		3
3-state 2-in-1 data selector MUX		4
3-state 2-in-1 data selector MUX, inverted out		4
3-state 2-input AND	3-state 2-input NOR, both inputs inverted	5
3-state 2-input AND, one input inverted	3-state 2-input NOR, one input inverted	5
3-state 2-input AND, both inputs inverted	3-state 2-input NOR	5
3-state 2-input NAND	3-state 2-input OR, both inputs inverted	6
3-state 2-input NAND, one input inverted	3-state 2-input OR, one input inverted	6
3-state 2-input NAND, both inputs inverted	3-state 2-input OR	6
3-state 2-input XOR		7
3-state 2-input XNOR	3-state 2-input XOR, one input inverted	7

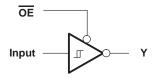
3-STATE BUFFER FUNCTIONS AVAILABLE



FUNCTION	ŌĒ	Α	В	С	D
		Input	H or L	L	L
		H or L	Input	Н	L
		L	Н	Input	L
3-state buffer	L	Н	L	Input	Н
		Н	H or L	L	Input
		H or L	L	Н	Input
		L	L	H or L	Input

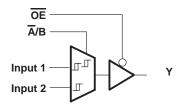


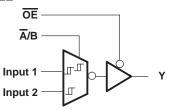
3-STATE INVERTER FUNCTIONS AVAILABLE



FUNCTION	ŌĒ	Α	В	С	D
		Input	H or L	L	Н
		Х	Input	Н	Н
		L	L H Input	Н	
3-state inverter	L	Н	L	Input	L
		Н	H or L	L	Input
		H or L	Н	Н	Input
		Н	Н	H or L	Input

3-STATE MUX FUNCTIONS AVAILABLE



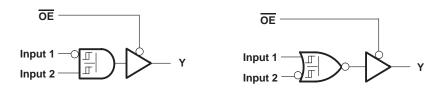


FUNCTION	ŌĒ	Α	В	С	D
3-state 2-to-1		Input 1	Input 2	Input 1 or Input 2	L
3-state 2-to-1		Input 2	Input 1	Input 2 or Input 1	L
3-state 2-to-1	L	Input 1	Input 2	Input 1 or Input 2	Н
3-state 2-to-1		Input 2	Input 1	Input 2 or Input 1	Н

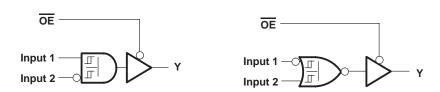
3-STATE AND/NOR FUNCTIONS AVAILABLE



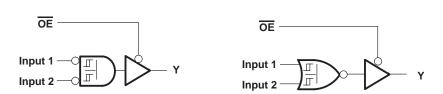
NO. OF INPUTS	AND/NAND FUNCTION	OR/NOR FUNCTION	ŌĒ	Α	В	С	D
2	3-state AND	3-state NOR		L	Input 1	Input 2	L
2	3-state AND	3-state NOR	L	L	Input 2	Input 1	L



NO. OF INPUTS	AND/NAND FUNCTION	OR/NOR FUNCTION	OE	Α	В	С	D
2	3-state AND	3-state NOR		Input 2	L	Input 1	L
2	3-state AND	3-state NOR]	Н	Input 1	Input 2	Н



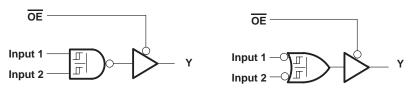
NO. OF INPUTS	AND/NAND FUNCTION	OR/NOR FUNCTION	OE	Α	В	C	D
2	3-state AND	3-state NOR		Input 1	L	Input 2	L
2	3-state AND	3-state NOR	L	Н	Input 2	Input 1	Н



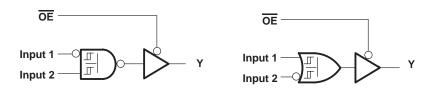
NO. OF INPUTS	AND/NAND FUNCTION	OR/NOR FUNCTION	OE	Α	В	С	D
2	3-state AND	3-state NOR		Input 1	Η	Input 2	L
2	3-state AND	3-state NOR	L	Input 2	Н	Input 1	L



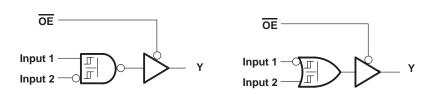
3-STATE NAND/OR FUNCTIONS AVAILABLE



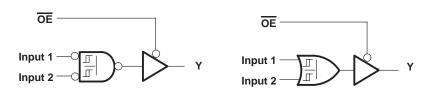
NO. OF INPUTS	AND/NAND FUNCTION	OR/NOR FUNCTION	ŌĒ	Α	В	С	D
2	3-state NAND	3-state OR		L	Input 1	Input 2	Н
2	3-state NAND	3-state OR	L	L	Input 2	Input 1	Н



NO. OF INPUTS	AND/NAND FUNCTION	OR/NOR FUNCTION	OE	Α	В	С	D
2	3-state NAND	3-state OR		Input 2	L	Input 1	Н
2	3-state NAND	3-state OR	L	Н	Input 1	Input 2	L

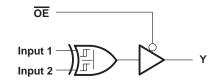


NO. OF INPUTS	AND/NAND FUNCTION	OR/NOR FUNCTION	OE	Α	В	C	D
2	3-state NAND	3-state OR		Input 1	L	Input 2	Н
2	3-state NAND	3-state OR	L	Н	Input 2	Input 1	L

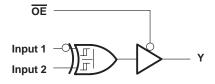


NO. OF INPUTS	AND/NAND FUNCTION	OR/NOR FUNCTION	OE	Α	В	С	D
2	3-state NAND	3-state OR		Input 1	Н	Input 2	L
2	3-state NAND	3-state OR	L	Input 2	Н	Input 1	L

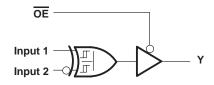
3-STATE XOR/XNOR FUNCTIONS AVAILABLE



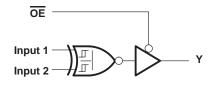
FUNCTION	ŌĒ	Α	В	С	D
		Input 1	H or L	L	Input 2
		Input 2	H or L	L	Input 1
3-state XOR	L	H or L	Input 1	Н	Input 2
3-state XOR		H or L	Input 2	Н	Input 1
		L	Н	Input 1	Input 2
		L	Н	Input 2	Input 1



FUNCTION	OE	Α	В	С	D
3-state XOR	L	Н	L	Input 1	Input 2



FUNCTION	E	Α	В	C	D
3-state XOR	L	Н	L	Input 1	Input 2



FUNCTION	OE	Α	В	C	D
3-state XNOR	1	Н	L	Input 1	Input 2
3-state XNOR	L	Н	L	Input 2	Input 1



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high-impedance or power-off	state, V _O
(see Note 1)	0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	\dots -0.5 V to V _{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, IO	
Continuous current through V _{CC} or GND	
Package thermal impedance, θ _{JA} (see Note 3): DCT package	220°C/W
DCU package	227°C/W
	102°C/W
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The value of V_{CC} is provided in the recommended operating conditions table.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
.,		Operating	1.65	5.5	
VCC	Supply voltage	Data retention only	1.5		V
VI	Input voltage		0	5.5	V
٧o	Output voltage		0	VCC	V
		V _{CC} = 1.65 V		-4	
		V _{CC} = 2.3 V		-8	
lOH	High-level output current	V 0V		-16	mA
		VCC = 3 V		-24	
		V _{CC} = 4.5 V		-32	
		V _{CC} = 1.65 V		4	
		V _{CC} = 2.3 V		8	
loL	Low-level output current	V 2V		16	mA
		VCC = 3 V		24	
		V _{CC} = 4.5 V		32	
		V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC} = 5 V \pm 0.5 V$		5	

NOTE 4: All unused inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	VCC	MIN	TYP [†] MAX	UNIT
		1.65 V	0.79	1.26	
V _{T+}		2.3 V	1.11	1.66	
Positive-going input threshold		3 V	1.5	1.97	V
voltage		4.5 V	2.16	2.84	
		5.5 V	2.61	3.43	
		1.65 V	0.39	0.72	
VT-		2.3 V	0.58	0.97	
Negative-going input threshold		3 V	0.84	1.24	V
voltage		4.5 V	1.41	1.89	
		5.5 V	1.87	2.39	
		1.65 V	0.37	0.72	
ΔV_T		2.3 V	0.48	0.87	
Hysteresis		3 V	0.56	0.97	V
$(V_{T+} - V_{T-})$		4.5 V	0.71	1.14	
		5.5 V	0.71	1.21	
	$I_{OH} = -100 \mu\text{A}$	1.65 V to 5.5 V	V _{CC} - 0.1		
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		
VOH	$I_{OH} = -16 \text{ mA}$	3 V	2.4		V
	I _{OH} = -24 mA	3 V	2.3]
	I _{OH} = -32 mA	4.5 V	3.8		
	I _{OL} = 100 μA	1.65 V to 5.5 V		0.1	
	$I_{OL} = 4 \text{ mA}$	1.65 V		0.45	
	$I_{OL} = 8 \text{ mA}$	2.3 V		0.3	
VOL	$I_{OL} = 16 \text{ mA}$			0.4	V
	I _{OL} = 24 mA	3 V		0.55	
	I _{OL} = 32 mA	4.5 V		0.55	
ΙΙ	V _I = 5.5 V or GND	0 to 5.5 V		±5	μΑ
l _{off}	V_I or $V_O = 5.5 V$	0		±10	μΑ
loz	$V_O = V_{CC}$ or GND	1.65 V to 5.5 V		±10	μΑ
ICC	$V_I = 5.5 \text{ V or GND}, \qquad I_O = 0$	1.65 V to 5.5 V		10	μΑ
ΔlCC	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	3 V to 5.5 V		500	μΑ
C _i	$V_I = V_{CC}$ or GND	3.3 V		3.5	pF
Co	$V_O = V_{CC}$ or GND	3.3 V		6	pF

[†]T_A = 25°C



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switching characteristics over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} =		V _{CC} =		ν _{CC} =		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Α		4.5	30.1	2.5	11.3	1.8	7.5	1.3	4.8	
4 .	В		4.4	28.3	2.4	10.8	1.8	7.2	1.3	4.7	
^t pd	С	Ť	4.4	29.1	2.4	11.7	1.9	7.6	1.3	5	ns
	D	1 [4.3	25.1	2.4	10.2	1.7	6.7	1.3	4.5	
ten	ŌĒ	Y	3.4	24.7	2.1	10	1.3	5.8	1	3.8	ns
t _{dis}	ŌĒ	Y	4	15.5	2.7	7.5	3.5	7	2	5.5	ns

switching characteristics over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 2)

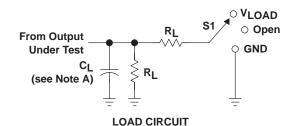
PARAMETER	FROM	FROM TO		V _{CC} = 1.8 V V _{CC} = 2.5 V ± 0.15 V ± 0.2 V			V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	А		4.6	30.8	2.6	11.7	2.4	8.4	1.8	5.5	
4 .	В	_	4.6	28.9	2.6	11.3	2.3	8.2	1.8	5.4	
^t pd	С	Υ	4.4	29.8	2.5	12.3	2.5	8.6	1.8	5.7	ns
	D		4.3	25.7	2.5	10.7	2.4	7.6	1.6	5.2	
t _{en}	ŌĒ	Y	4.2	25.2	2.4	11.3	2	7	1.7	4.7	ns
t _{dis}	ŌĒ	Y	3.7	15	2	5.8	2.1	5.6	1	4.5	ns

operating characteristics, $T_A = 25^{\circ}C$

PARAMETER		TEST	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	V _{CC} = 5 V	
		CONDITIONS	TYP	TYP	TYP	TYP	UNIT
C _{pd}	Power dissipation capacitance	f = 10 MHz	19	20	22	27	pF



PARAMETER MEASUREMENT INFORMATION



5 V \pm 0.5 V

TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	VLOAD
^t PHZ ^{/t} PZH	GND

0.3 V

	INPUTS					_	.,
VCC	٧ı	t _r /t _f	VM	VLOAD	CL	RL	$oldsymbol{V}_\Delta$
1.8 V ± 0.15 V	VCC	≤2 ns	V _{CC} /2	2×V _{CC}	15 pF	1 M Ω	0.15 V
2.5 V \pm 0.2 V	VCC	≤2 ns	V _{CC} /2	2×V _{CC}	15 pF	1 M Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 M Ω	0.3 V

2×V_{CC}

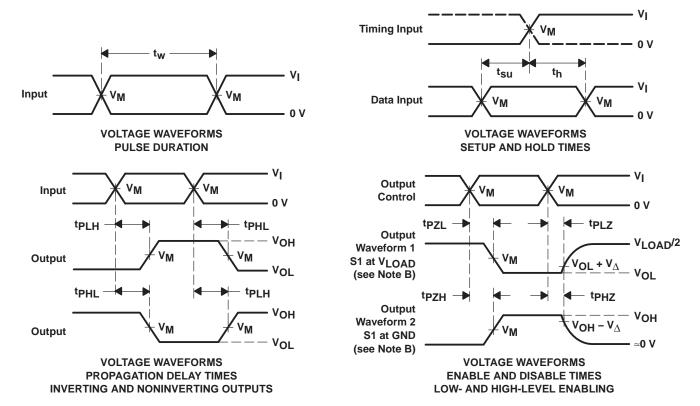
15 pF

1 $M\Omega$

V_{CC}/2

≤2.5 ns

VCC



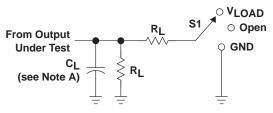
NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Ω = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



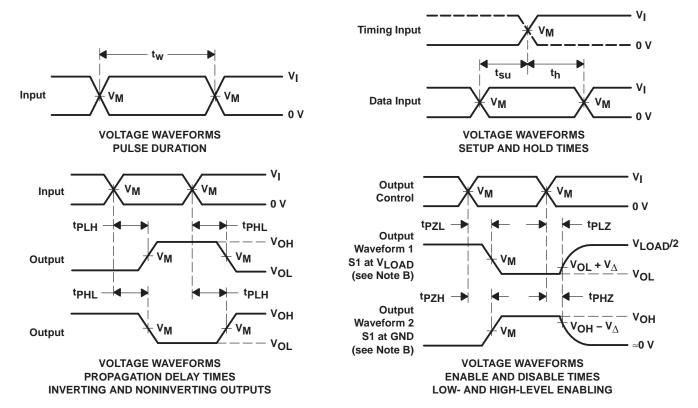
PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	VLOAD
tPHZ/tPZH	GND

10	ΔD	CIR	CI	IIT
LU	AD	CIL	υı	<i>7</i> 11

.,	INF	PUTS	.,	V	•	В.	V
VCC	٧ _I	t _r /t _f	VM	VLOAD	CL	RL	$v_{\scriptscriptstyle\Delta}$
1.8 V \pm 0.15 V	VCC	≤ 2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	VCC	≤ 2 ns	V _{CC} /2	2×VCC	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V \pm 0.5 V	VCC	≤2.5 ns	V _{CC} /2	2×V _{CC}	50 pF	500 Ω	0.3 V



- NOTES: A. C_I includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Ω = 50 Ω.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. tpLZ and tpHZ are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms







.com 17-Mar-2006

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LVC1G99DCTR	ACTIVE	SM8	DCT	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G99DCTT	ACTIVE	SM8	DCT	8	250	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G99DCTTE4	ACTIVE	SM8	DCT	8	250	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G99DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G99DCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G99DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G99DCUTE4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G99YEPR	NRND	WCSP	YEP	8	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74LVC1G99YZPR	ACTIVE	WCSP	YZP	8	3000	Pb-Free (RoHS)	SNAGCU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

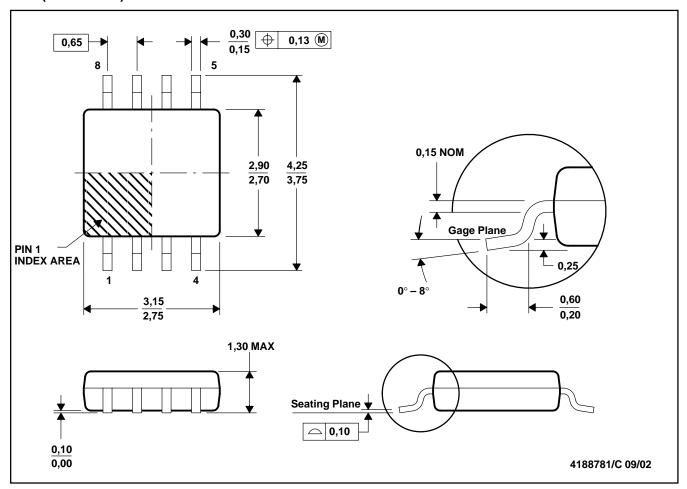
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

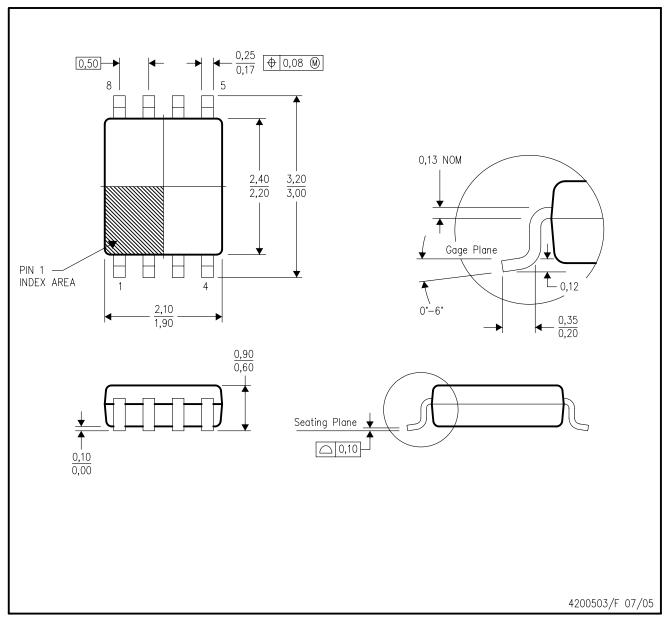


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion
- D. Falls within JEDEC MO-187 variation DA.

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



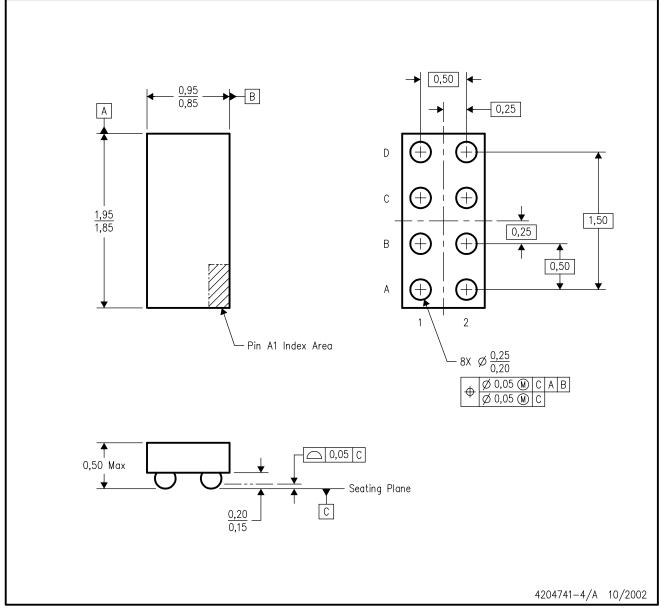
NOTES:

- : A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-187 variation CA.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

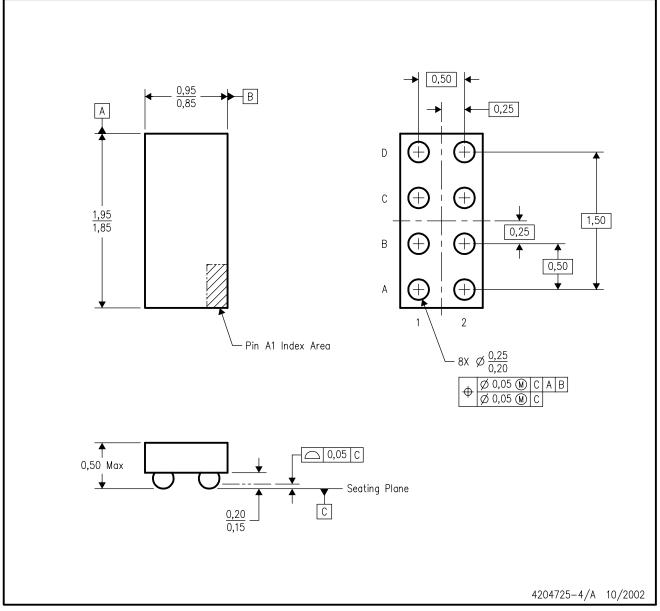
- B. This drawing is subject to change without notice.
- C. NanoFree $^{\text{TM}}$ package configuration.
- D. This package is lead-free. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



YEP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoStar \mathbf{M} package configuration.
- D. This package is tin-lead (SnPb). Refer to the 8 YZP package (drawing 4204741) for lead-free.

NanoStar is a trademark of Texas Instruments.



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